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Central Intelligence Agency



DIRECTORATE OF INTELLIGENCE.

23 May 1984

MEMORANDUM FOR:

Mr. Donald Anderson

Director, Office of Chinese Affairs

Department of State

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FROM:

Chief, China Division

Office of East Asian Analysis

SUBJECT:

Sales of PRC Electronic Grade Silicon

to the USSR

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We reviewed the question of possible sales of PRC electronic grade silicon to the USSR in our memo to Assistant Secretary Wolfowitz of 11 August 1983 (attached).

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SUBJECT: Sales of PRC Electronic Grade Silicon to the USSR

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National Security Council

1 - David Laux, Senior Staff Assistant for China, Taiwan and Hong Kong

Department of State

2 - Donald Anderson, Director, Office of Chinese Affairs

Department of Commerce

3 - Eugene K. Lawson, Deputy Assistant Secretary for East Asia and Pacific

Department of Defense

- 4 Stephen D. Bryen, Deputy Assistant Secretary for Economic Trade, and Security Policy
- 5 Steward A. Ring, USN, Director, East Asia and Pacific Region

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Central Intelligence Agency



DIRECTORATE OF INTELLIGENCE

1 1 AUG 1983

MEMORANDUM FOR:

Mr. Paul Wolfowitz

Assistant Secretary of State for East Asian and Pacific Affairs

Department of State

FROM:

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Deputy Director of East Asian Analysis

SUBJECT:

China/USSR: Production and Imports of

Electronic Grade Silicon

In response to your request for information on Soviet production and imports of electronic grade silicon, and the availability and quality of Chinese material, we are providing the following information.

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Background

While we cannot confirm a sale, a COCOM ally recently suggested that PRC-origin single crystal silicon wafers, produced with US-supplied manufacturing machinery, may be finding their way to the USSR through third country intermediaries. We also are reminded of an earlier reservation by another COCOM member to the US sale of crystal growing furnaces to China in early 1981, and the need for a licensing requirement stating that the silicon produced with this equipment be used for Chinese domestic consumption only and not be exported.

The USSR and other Warsaw Pact states have chronic shortages of electronic grade silicon. The COCOM embargo on both silicon and the machinery used to produce it, however, has prevented the USSR from tapping the ample supplies available from Western and Japanese producers. The PRC has surplus supplies of electronic grade silicon and Chinese trade officials and silicon producers may see the USSR as a potentially lucrative outlet for these surpluses.

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China's negotiations for possible sales of wafers probably were arranged under general guidelines that encourage all Chinese industrial enterprises to increase export earnings. It is highly doubtful, however, that the Chinese leadership would authorize a sale that enhanced Soviet military capabilities. We believe 25X1

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these transactions—like some aspects of China's sale of nuclear materials—suggest that some elements of the bureaucracy, including probably the Foreign Ministry are not always included in decisions of this kind.

Soviet Production of Silicon

Soviet production of electronic grade silicon (both polycrystalline and monocrystalline) is well below domestic consumption. We estimate that as of early 1982 the USSR had a production capacity of about 300 metric tons of polysilicon per year. At the same time, domestic consumption of polycrystalline silicon in the Soviet Union was estimated at 500 metric tons a year which is roughly equivalent to 250 tons of monocrystalline silicon or single crystal material (see attached Chart). The gap between consumption and production—about 200 metric tons or 40% of domestic needs—was filled by imports from the West.

The quality of Soviet-made silicon is believed to be inferior to that which is imported, and inadequate for the production of various types of advanced devices. Hence, the Soviets probably use imported silicon to improve production yields and to produce its most advanced types of microelectronics. Domestically produced material is probably used in the manufacture of more conventional lower priority items.

Imports

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The USSR has been importing Western electronic grade silicon in significant quantities since about 1975. Soviet purchases prior to this were sporadic and of negligible quantities. The surge in silicon imports since 1975—directly related to the rapid growth in Soviet semiconductor production—has outstripped the growth in capacity of domestic silicon producers. Also, the rapid pace in Soviet integrated circuit development to support both military and civilian needs generated requirements for silicon purity levels and varieties of material beyond the existing capability of the domestic producer.

Controls.

Prior to 1980, existing COCOM controls on electronic grade silicon enabled the USSR to purchase virtually all the materials that it required. Following the Afghanistan invasion, greater restriction was placed on silicon exports to the USSR, and COCOM agreement was obtained to tighten silicon controls—although at a somewhat less restrictive level than the US had requested. The COCOM action, referred to as the "1980 Compromise", left significant gaps in the control of silicon material exports:

o <u>Polysilicon</u> - Controls appeared to cover only the material. It was not clearly stated whether the technology to produce polycrystalline silicon was also proscribed.

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	o Moi	nosilicon ingots	- Exports of	f ingots were	controlled.
Ιt	was not	clear, however,	whether the	technology a	nd equipment
to	produce	monocrystalline	silicon was	also proscri	bed.

Monosilicon wafers - Wafers were only p	
controlled. For example, through "Administrati	ve Exception
Notes" the following types of wafers could be e	xported: all "N"
type 1-1-1 material; a large part of "P" type 1	-1-1 material: and
a small part of "N" type 1-0-0 material. Thus.	only "P" type 1-
0-0 material was tightly controlled.	25X′

appeared to have only limited effect in curtailing exports of silicon wafers to the USSR. Many violations went undetected because the technical detail needed to determine the exportability of a specific wafer

Also, when there was evidence to suggest that at 25X1

Teast some of the wafers were restricted and were being shipped illegally, exporting countries would claim that only exportable types under the "Administrative Exception Notes" or non-embargoed material were being sold.

The modified controls emanating from the "1980 Compromise"

China's Silicon Offer

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The COCOM regulation states that monocrystalline silicon in the form of wafers (slices) or ingots (boules) having a 25X1 resistivity of 50 ohms centimeter or less for all "N" type and for "P" type 1-1-1, or 100 ohms centimeter or less for "P" type 1-0-0 are restricted.

We might further note that prior to 1982 there was no evidence of a Chinese offer or sale of monocrystalline silicon wafers outside of the PRC. As indicated in our previous memoranda, China has sold polycrystalline silicon material abroad including some supplied to the USSR. Until recently China has only been able to produce silicon wafers with diameters of 1.5 25X1 2.0 inches. These generally were of uneven quality and not acceptable on the international market.

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Silicon Production Process